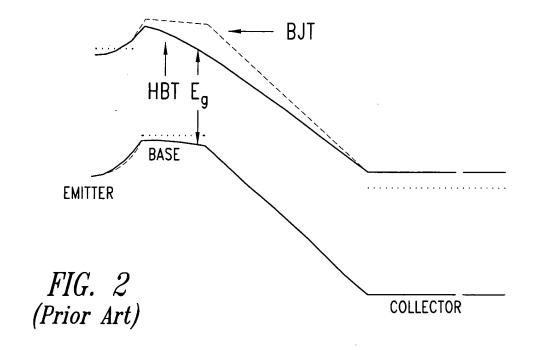
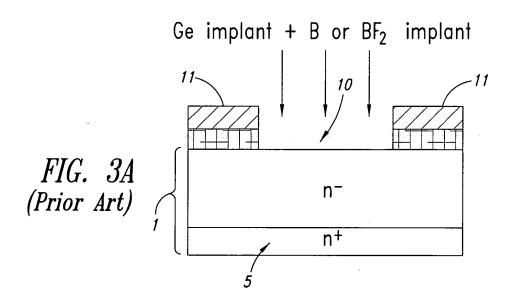
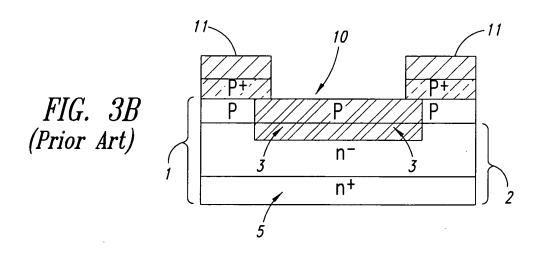
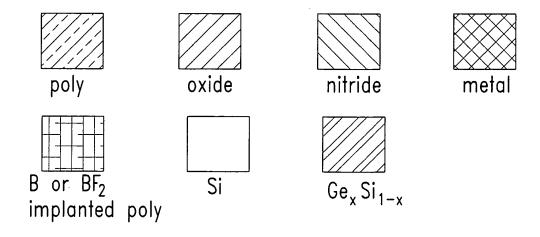


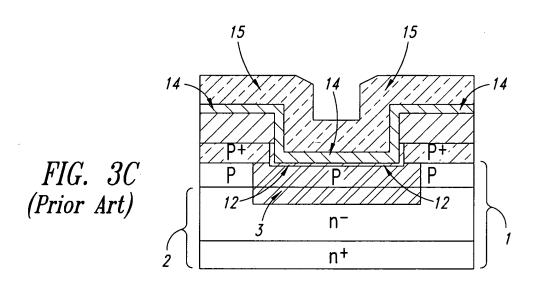
FIG. 1 (Prior Art)

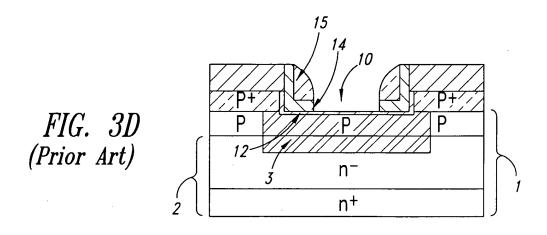


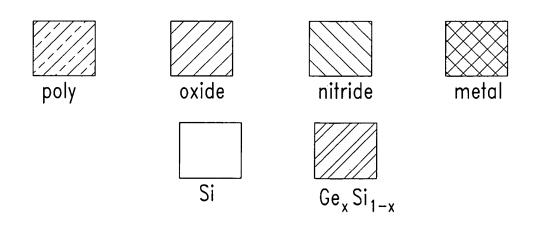


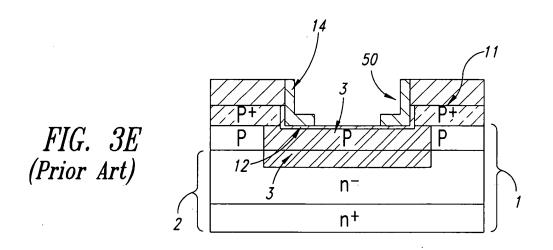


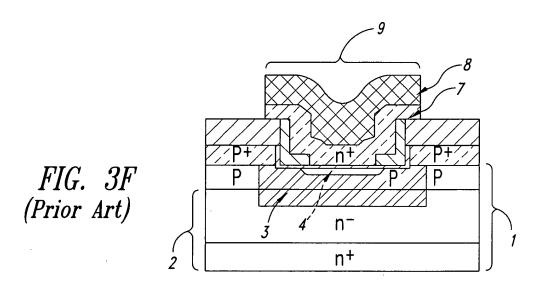


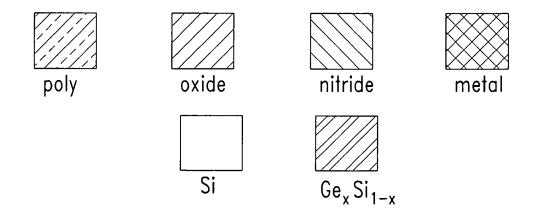












—— T1: 2 X 7.4 μm² ---- T2: 0.4 X 7.4 μm²

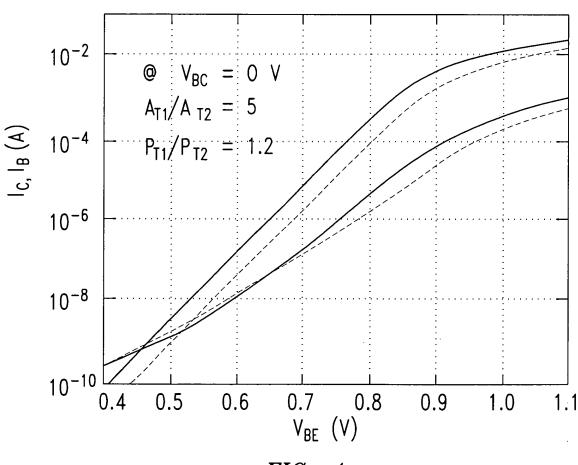
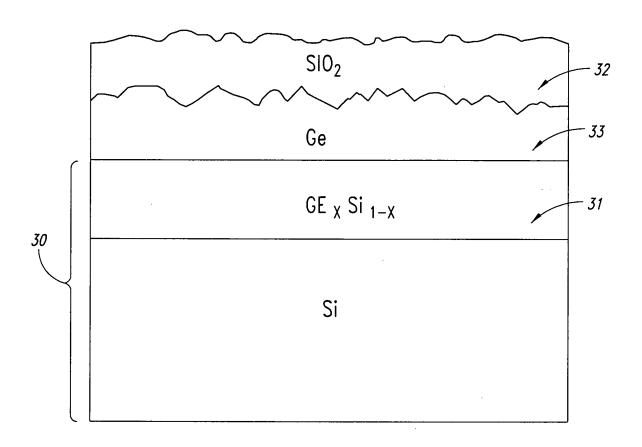


FIG. 4



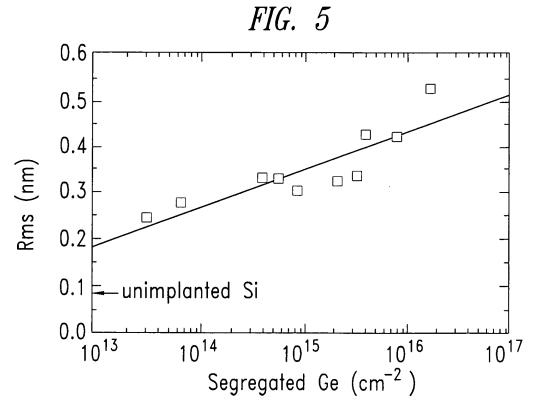


FIG. 7

Thermal oxide in Ge_xSi_{1-x}

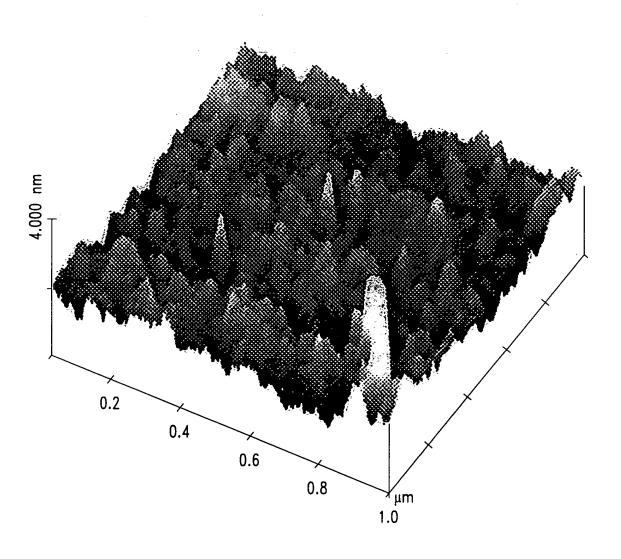
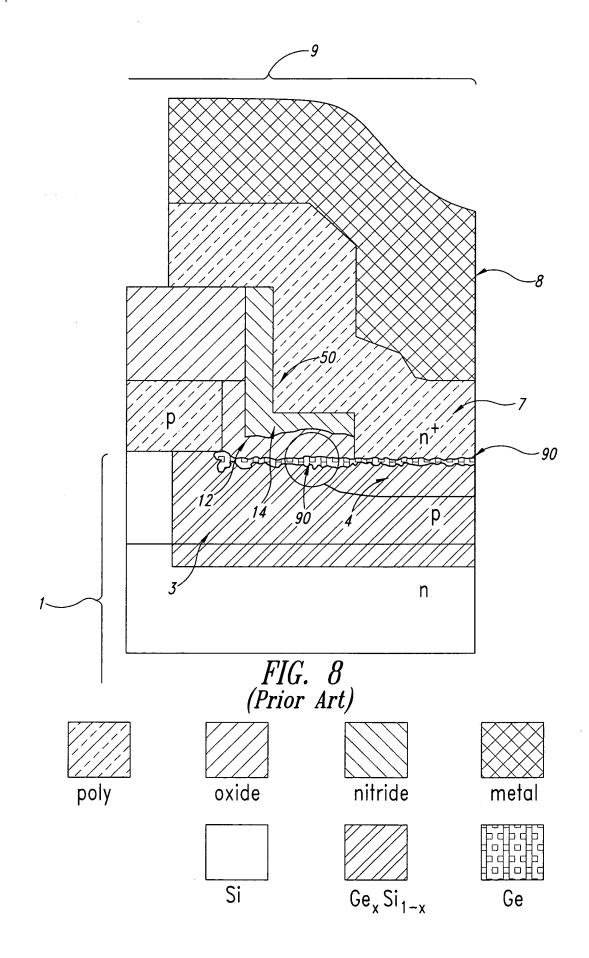


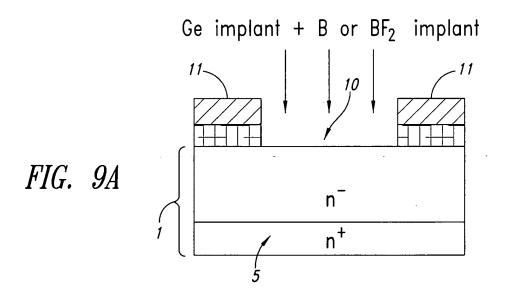
FIG. 6

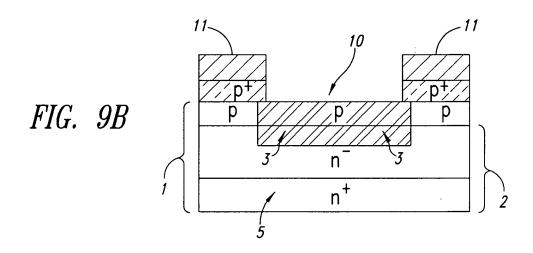
poly

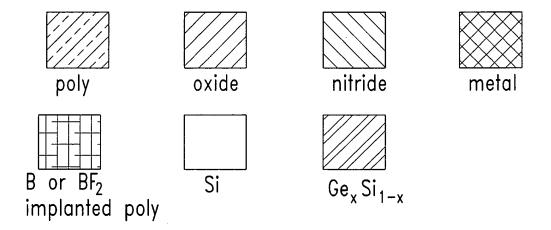


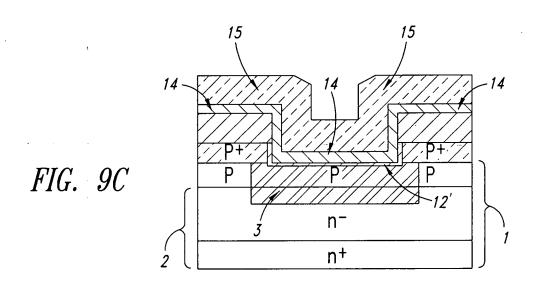
Serial No. 10/615,084 Docket No. 856063.547D1 Inventor(s): Salvatore Lombardo et al.

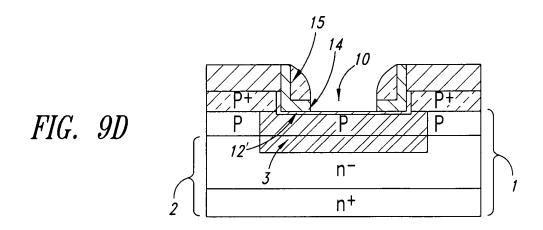
Express Mail No. EV530951119US "REPLACEMENT SHEET"

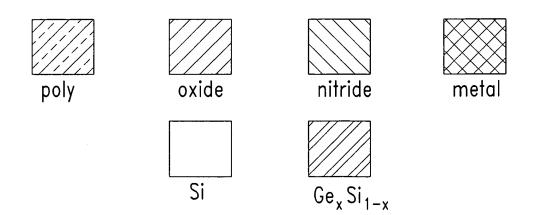


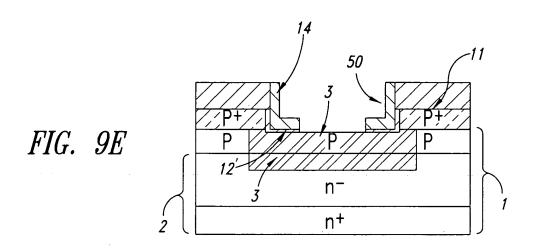


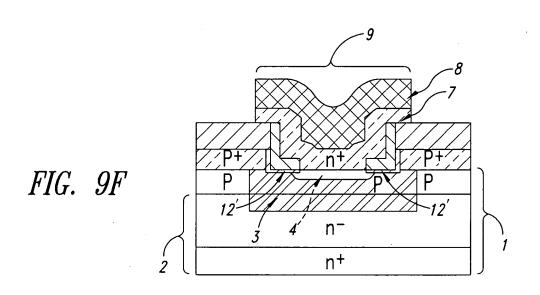


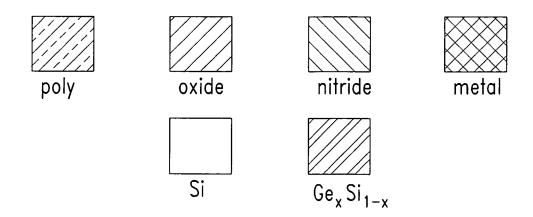












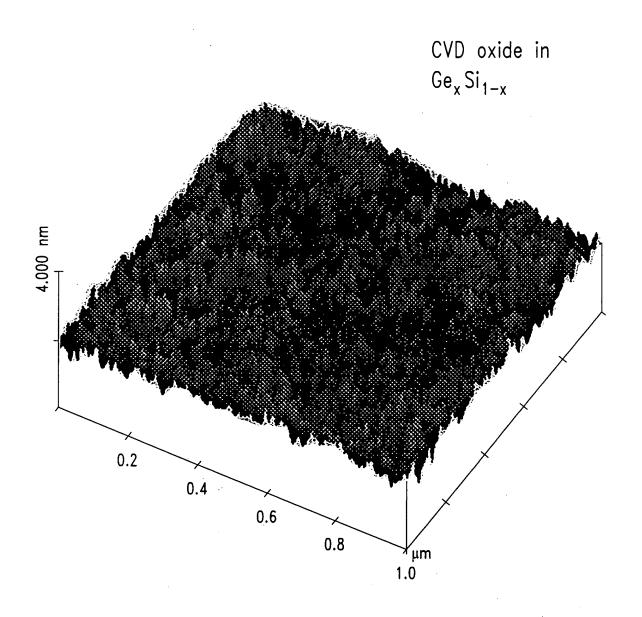


FIG. 10

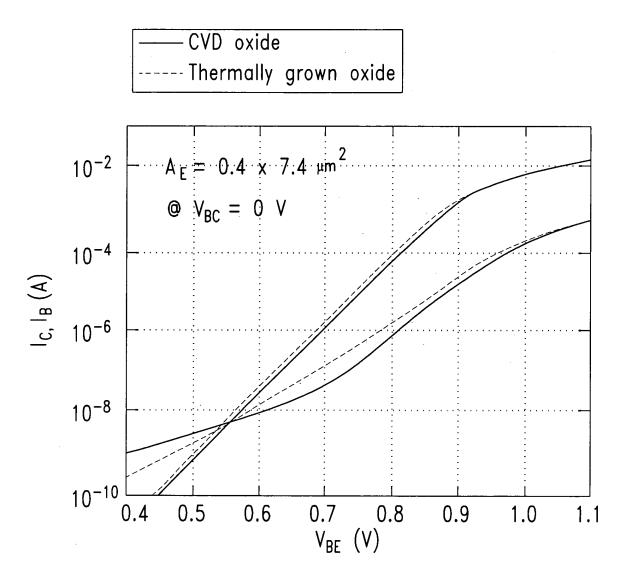
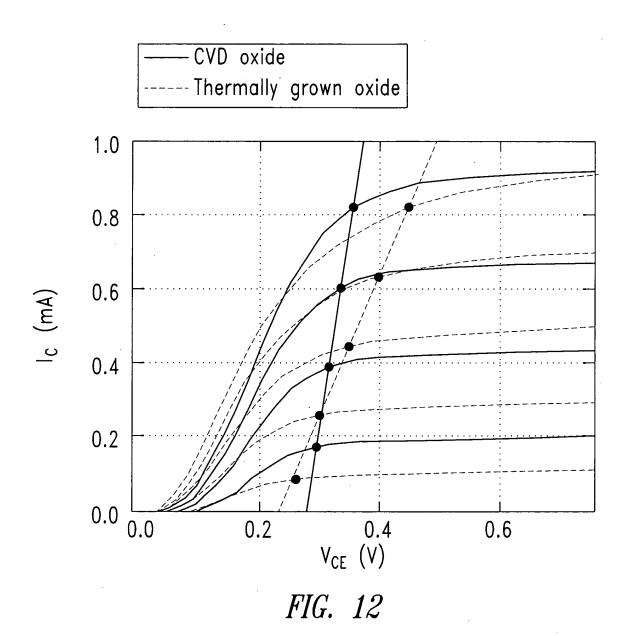


FIG. 11



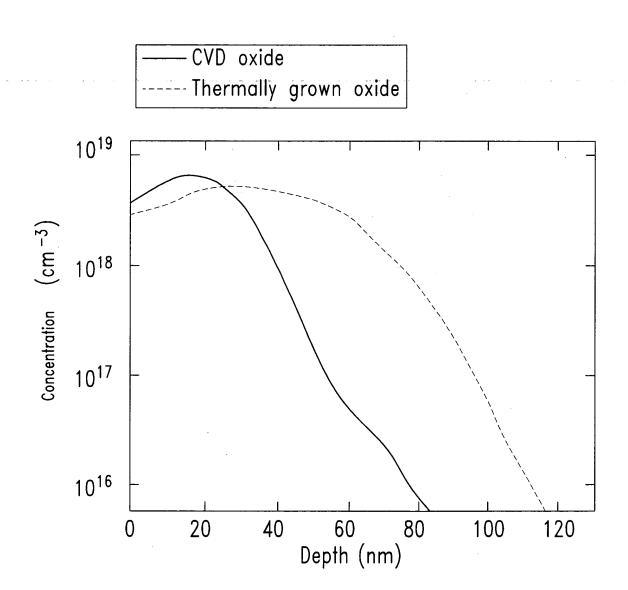


FIG. 13

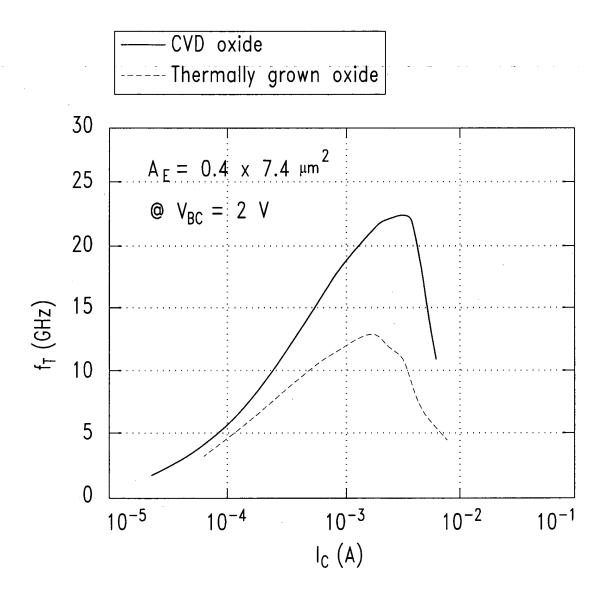


FIG. 14